Preferred Device

SWITCHMODE™ Power Rectifier

These state—of—the—art devices are designed for use in negative switching power supplies, inverters and as free wheeling diodes. Also, used in conjunction with common cathode dual Ultrafast Rectifiers, makes a single phase full—wave bridge.

Features

- Common Anode Dual Rectifier (8.0 A per Leg or 16 A per Package)
- Ultrafast 35 Nanosecond Reverse Recovery Times
- Exhibits Soft Recovery Characteristics
- High Temperature Glass Passivated Junction
- Low Leakage Specified @ 150°C Case Temperature
- Current Derating @ Both Case and Ambient Temperatures
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Complement to MUR1620CT and MURB1620CT Common Cathode Device
- Pb-Free Packages are Available

Mechanical Characteristics:

- Case: Epoxy, Molded
- Weight: MUR1620CTR: 1.9 Grams (Approximately)
 MURB1620CTR: 1.7 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds

MAXIMUM RATINGS (Per Leg)

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	200	V
Average Rectified Forward Voltage (Rated V_R , $T_C = 160^{\circ}C$) Per Leg Per Total Device	I _{F(AV)}	8.0 16	Α
	I _{FM}	16	Α
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	I _{FSM}	100	Α
Operating Junction and Storage Temperature Range	T _J , T _{stg}	-65 to +175	°C

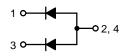
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



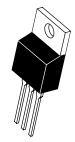
ON Semiconductor®

http://onsemi.com

ULTRAFAST RECTIFIER16 AMPERES, 200 VOLTS



MARKING DIAGRAMS



TO-220AB CASE 221A STYLE 7







U1620R = Device Code
KAK = Diode Polarity
A = Assembly Location

Y = Year WW = Work Week G = Pb-Free Package

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS (Per Leg)

Rating	Symbol	Value	Unit
Thermal Resistance, Junction-to-Case	$R_{ heta JC}$	2.0	°C/W

ELECTRICAL CHARACTERISTICS (Per Leg)

Rating	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 1) (i _F = 8.0 Amps, T_C = 25°C) (i _F = 8.0 Amps, T_C = 150°C)	VF	1.2 1.1	٧
Maximum Instantaneous Reverse Current (Note 1) (Rated dc Voltage, $T_C = 25^{\circ}C$) (Rated dc Voltage, $T_C = 150^{\circ}C$)	i _R	5.0 500	μΑ
Maximum Reverse Recovery Time ($I_F = 1.0 \text{ Amp}, \text{ di/dt} = 50 \text{ Amps/}\mu\text{s}$) ($I_F = 0.5 \text{ Amp}, \text{ di/dt} = 100 \text{ Amps/}\mu\text{s}$)	t _{rr}	85 35	ns

^{1.} Pulse Test: Pulse Width = 5.0 ms, Duty Cycle ≤ 10%.

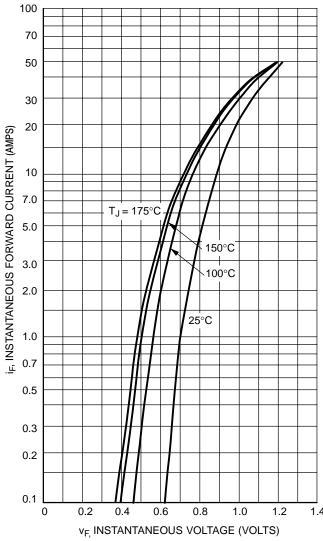


Figure 1. Typical Forward Voltage (Per Leg)

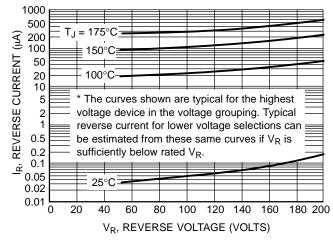


Figure 2. Typical Reverse Current* (Per Leg)

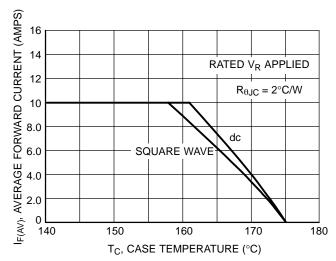


Figure 3. Current Derating, Case (Per Leg)

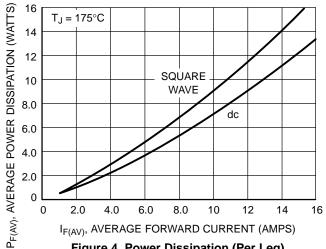


Figure 4. Power Dissipation (Per Leg)

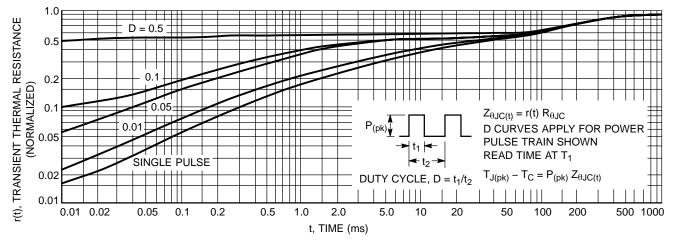


Figure 5. Thermal Response

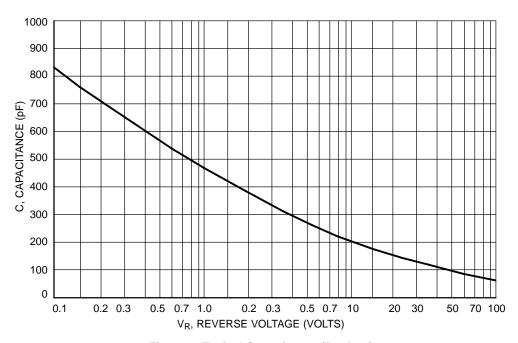


Figure 6. Typical Capacitance (Per Leg)

ORDERING INFORMATION

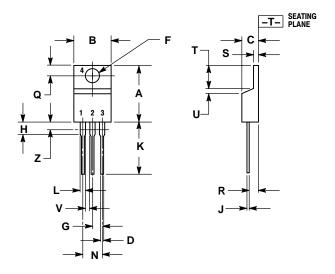
Device	Package	Shipping [†]
MUR1620CTR	TO-220	50 Units / Rail
MUR1620CTRG	TO-220 (Pb-Free)	50 Units / Rail
MURB1620CTR	D ² PAK-3	50 Units / Rail
MURB1620CTRG	D ² PAK-3 (Pb-Free)	50 Units / Rail
MURB1620CTRT4	D ² PAK-3	800 / Tape & Reel
MURB1620CTRT4G	D ² PAK-3 (Pb-Free)	800 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TO-220 THREE-LEAD TO-220AB

CASE 221A-09 **ISSUE AA**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

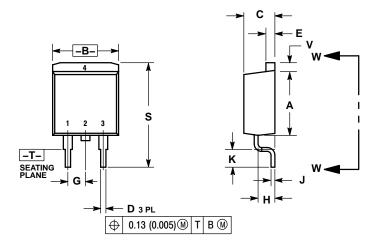
	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

- STYLE 7:
 PIN 1. CATHODE
 2. ANODE
 3. CATHODE

 - 4. ANODE

PACKAGE DIMENSIONS

D²PAK-3 CASE 418B-04 **ISSUE J**

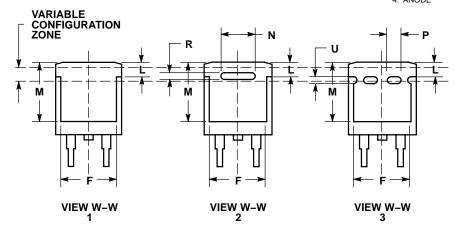


NOTES

- 1. DIMENSIONING AND TOLERANCING
- PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- 418B-01 THRU 418B-03 OBSOLETE, NEW STANDARD 418B-04.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.340	0.380	8.64	9.65
В	0.380	0.405	9.65	10.29
С	0.160	0.190	4.06	4.83
D	0.020	0.035	0.51	0.89
E	0.045	0.055	1.14	1.40
F	0.310	0.350	7.87	8.89
G	0.100 BSC		2.54 BSC	
Н	0.080	0.110	2.03	2.79
J	0.018	0.025	0.46	0.64
K	0.090	0.110	2.29	2.79
L	0.052	0.072	1.32	1.83
М	0.280	0.320	7.11	8.13
N	0.197 REF		5.00 REF	
Р	0.079 REF		F 2.00 REF	
R	0.039	REF	0.99 REF	
S	0.575	0.625	14.60	15.88
V	0.045	0.055	1.14	1.40

- STYLE 5: PIN 1. CATHODE
 - ANODE
 CATHODE
 - 4. ANODE



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